

MOS FIELD EFFECT TRANSISTOR 2SK3109

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3109 is N-channel MOS FET device that features a low on-state resistance and excellent switching characteristics, and designed for high voltage applications such as DC/DC converter.

ORDERING INFORMATION

PART NUMBER	PACKAGE		
2SK3109	TO-220AB (MP-25)		
2SK3109-S	TO-262 (MP-25 Fin Cut)		
2SK3109-ZJ	TO-263 (MP-25ZJ)		

FEATURES

- Gate voltage rating ±30 V
- Low on-state resistance
 R_{DS(on)} = 0.4 Ω MAX. (V_{GS} = 10 V, I_D = 5.0 A)
- Low input capacitance
 C_{iss} = 400 pF TYP. (V_{DS} = 10 V, V_{GS} = 0 V)
- · Avalanche capability rated
- Built-in gate protection diode
- Surface mount device available

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (V _{GS} = 0 V)	VDSS	200	V
Gate to Source Voltage (V _{DS} = 0 V)	Vgss	±30	V
Drain Current (DC) (Tc = 25°C)	I _{D(DC)}	±10	Α
Drain Current (pulse) Note1	I _D (pulse)	±30	Α
Total Power Dissipation (T _A = 25°C)	P _{T1}	1.5	W
Total Power Dissipation (Tc = 25°C)	P_{T2}	50	W
Channel Temperature	T_ch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	las	10	Α
Single Avalanche Energy Note2	Eas	35	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = 100 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V

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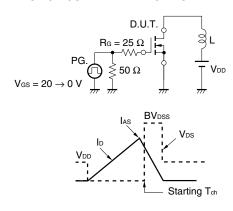


★ ELECTRICAL CHARACTERISTICS (T_A = 25°C)

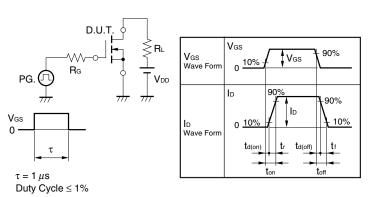
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 200 V, V _{GS} = 0 V			100	μΑ
Gate Leakage Current	Igss	V _{GS} = ±30 V, V _{DS} = 0 V			±10	μΑ
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	2.5		4.5	V
Forward Transfer Admittance Note	y fs	V _{DS} = 10 V, I _D = 5.0 A	1.5			S
Drain to Source On-state Resistance Note	RDS(on)	V _{GS} = 10 V, I _D = 5.0 A		0.32	0.4	Ω
Input Capacitance	Ciss	V _{DS} = 10 V,		400		pF
Output Capacitance	Coss	V _{GS} = 0 V,		110		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		55		pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 100 V, I _D = 5.0 A,		12		ns
Rise Time	tr	V _{GS} = 10 V,		34		ns
Turn-off Delay Time	t _{d(off)}	R _G = 10 Ω		40		ns
Fall Time	tf			20		ns
Total Gate Charge	QG	V _{DD} = 160 V,		18		nC
Gate to Source Charge	Qgs	V _{GS} = 10 V,		3.5		nC
Gate to Drain Charge	Q _{GD}	I _D = 10 A		10		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	I _F = 10 A, V _{GS} = 0 V		1.0		V
Reverse Recovery Time	trr	I _F = 10 A, V _{GS} = 0 V,		250		ns
Reverse Recovery Charge	Qrr	di/dt = 50 A/μs		1.0		μC

Note Pulsed

TEST CIRCUIT 1 AVALANCHE CAPABILITY

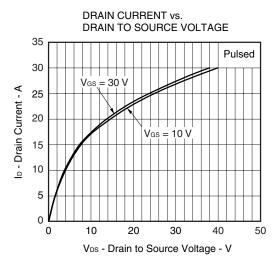


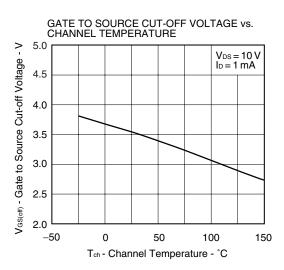
TEST CIRCUIT 2 SWITCHING TIME

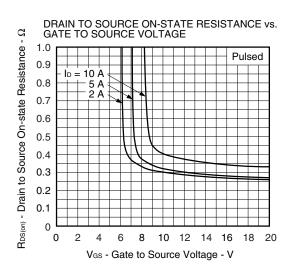


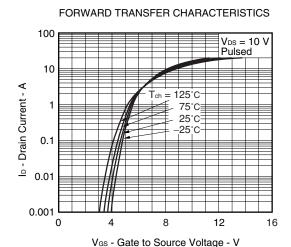
TEST CIRCUIT 3 GATE CHARGE

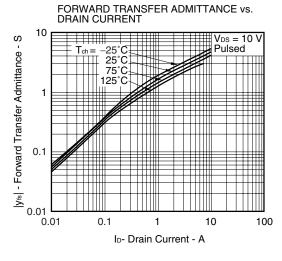
TYPICAL CHARACTERISTICS (TA = 25°C)

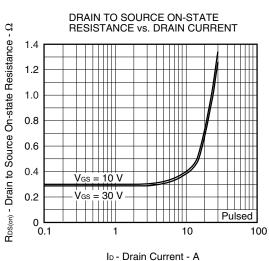




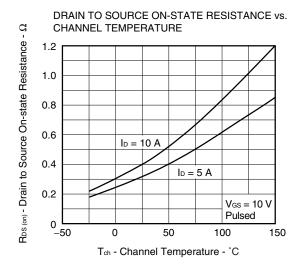


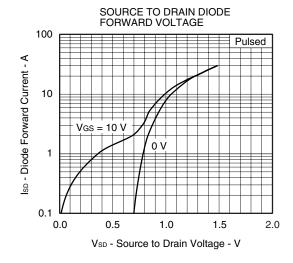


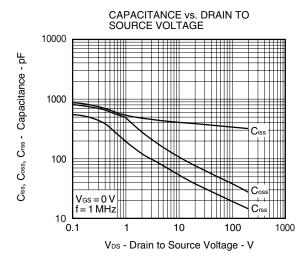


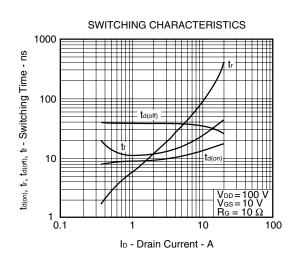


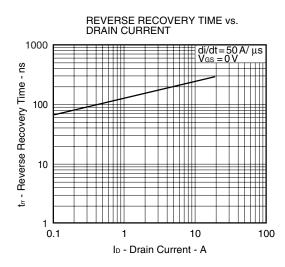
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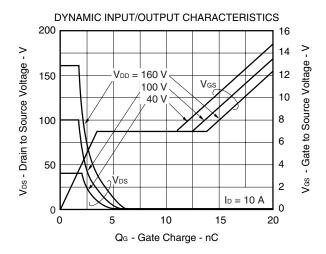


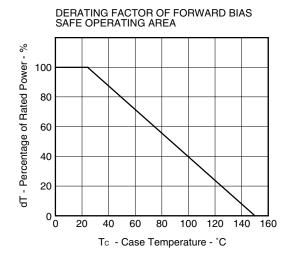


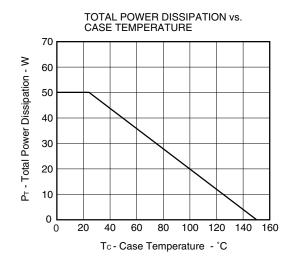




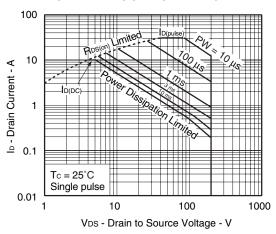




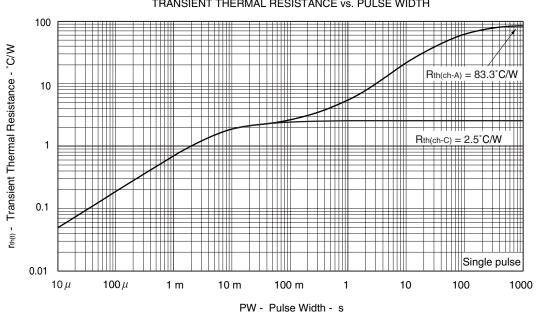




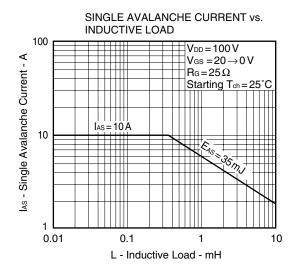
FORWARD BIAS SAFE OPERATING AREA

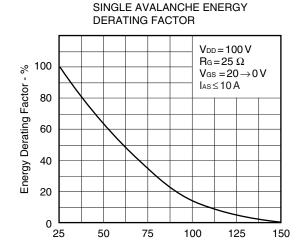


TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



5





75

100

Starting T_{ch} - Starting Channel Temperature - $^{\circ}\text{C}$

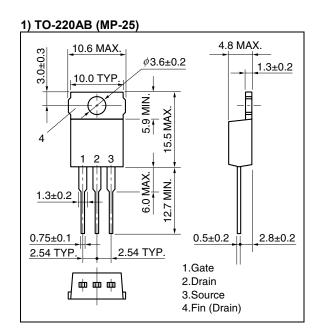
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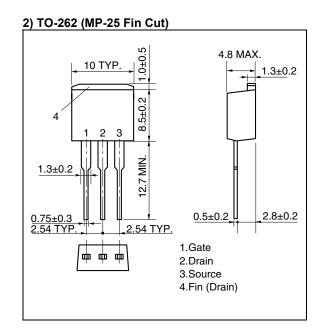
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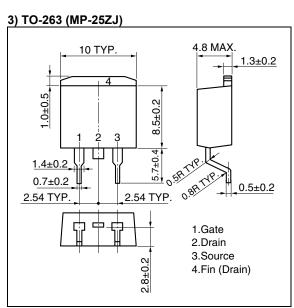
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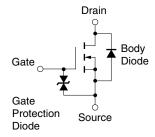
★ PACKAGE DRAWINGS (Unit: mm)







EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

Data Sheet D13332EJ3V0DS 7

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